



One Megabit per Second Triple Digital Isolators

Check for Samples: [ISO7230A](#), [ISO7231A](#)

FEATURES

- 1Mbps Signaling Rate
 - Low Channel-to-Channel Output Skew; 2ns Maximum (5V-Operation)
 - Low Pulse-Width Distortion (PWD); 10ns Maximum (5V-Operation)
- Typical 25-Year Life at Rated Working Voltage (See Application note [SLLA197](#) and [Figure 10](#))
- 4000V_{peak} Isolation, 560V_{peak} V_{IORM}
 - UL 1577, IEC 60747-5-2 (VDE 0884, Rev 2), IE 61010-1 and CSA Approved, IEC 60950-1
- 4kV ESD Protection
- Operate With 3.3V or 5V Supplies
- High Electromagnetic Immunity (See Application note [SLLA181](#))
- –40°C to 125°C Operating Range

APPLICATIONS

- Industrial Fieldbus
- Computer Peripheral Interface
- Servo Control Interface
- Data Acquisition

DESCRIPTION

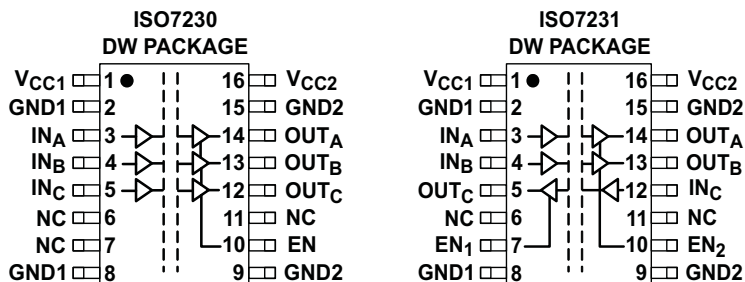
See the [Product Notification](#) section. The ISO7230A and ISO7231A are triple-channel digital isolators each with multiple channel configurations and output-enable functions. These devices have logic input and output buffers separated by TI's silicon dioxide (SiO₂) isolation barrier. Used in conjunction with isolated power supplies, these devices block high voltage, isolate grounds, and prevent noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry.

The ISO7230 triple-channel device has all three channels in the same direction while the ISO7231 has two channels in one direction and one channel in opposition. These devices have an active-high output enable that when driven to a low level, places the output in a high-impedance state.

The ISO7230A and ISO7231A have TTL input thresholds and a noise-filter at the input that prevents transient pulses of up to 2ns in duration from being passed to the output of the device.

In each device a periodic update pulse is sent across the isolation barrier to ensure the proper dc level of the output. If this dc-refresh pulse is not received, the input is assumed to be unpowered or not being actively driven, and the failsafe circuit drives the output to a logic high state. (Contact TI for a logic low failsafe option).

These devices require two supply voltages of 3.3V, 5V, or any combination. All inputs are 5V tolerant when supplied from a 3.3V supply and all outputs are 4mA CMOS. These devices are characterized for operation over the ambient temperature range of –40°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

**ISO7230A
ISO7231A**

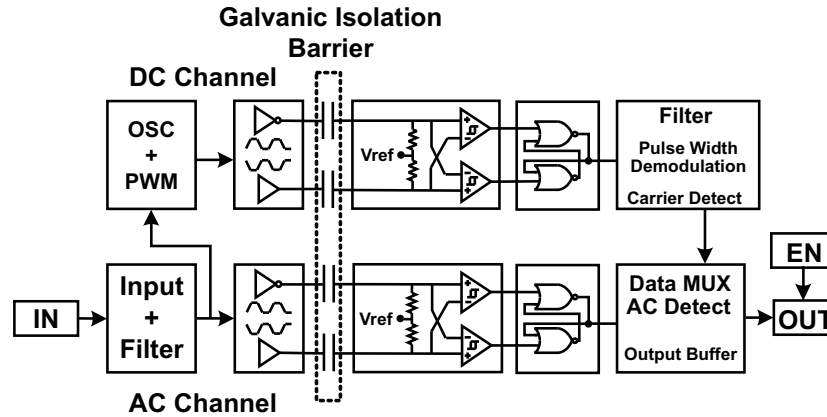
SLLS906C –MAY 2008–REVISED JUNE 2011

www.ti.com



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FUNCTION DIAGRAM

Table 1. Device Function Table ISO723x ⁽¹⁾

| INPUT V_{CC} | OUTPUT V_{CC} | INPUT (IN) | OUTPUT ENABLE (EN) | OUTPUT (OUT) |
|----------------|-----------------|------------|--------------------|--------------|
| PU | PU | H | H or Open | H |
| | | L | H or Open | L |
| | | X | L | Z |
| | | Open | H or Open | H |
| PD | PU | X | H or Open | H |
| PD | PU | X | L | Z |

(1) PU = Powered Up; PD = Powered Down ; X = Irrelevant; H = High Level; L = Low Level

AVAILABLE OPTIONS

| PRODUCT | SIGNALING RATE | INPUT THRESHOLD | CHANNEL CONFIGURATION | MARKED AS | ORDERING NUMBER ⁽¹⁾ |
|------------|----------------|-----------------------------------|-----------------------|-----------|--------------------------------|
| ISO7230ADW | 1 Mbps | ~1.5V (TTL) (CMOS compatible) | 3/0 | ISO7230A | ISO7230ADW (rail) |
| | | | | | ISO7230ADWR (reel) |
| ISO7231ADW | 1 Mbps | ~1.5 V (TTL) (CMOS compatible) | 2/1 | ISO7231A | ISO7231ADW (rail) |
| | | | | | ISO7231ADWR (reel) |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

| | | | | VALUE | UNIT | |
|-----------------|---|------------------------------------|--|-----------|------|----|
| V _{CC} | Supply voltage ⁽²⁾ , V _{CC1} , V _{CC2} | | | −0.5 to 6 | V | |
| V _I | Voltage at IN, OUT, EN | | | −0.5 to 6 | V | |
| I _O | Output current | | | ±15 | mA | |
| ESD | Electrostatic discharge | Human Body Model | JEDEC Standard 22, Test Method A114-C.01 | All pins | ±4 | kV |
| | | Field-Induced-Charged Device Model | JEDEC Standard 22, Test Method C101 | | ±1 | |
| | | Machine Model | ANSI/ESDS5.2-1996 | | ±200 | V |
| T _J | Maximum junction temperature | | | 170 | °C | |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal and are peak voltage values.

RECOMMENDED OPERATING CONDITIONS

| | | MIN | TYP | MAX | UNIT |
|-------------------|---|------|---------------------|-----------------|------|
| V _{CC} | Supply voltage ⁽¹⁾ , V _{CC1} , V _{CC2} | 3.15 | | 5.5 | V |
| I _{OH} | High-level output current | –4 | | | mA |
| I _{OL} | Low-level output current | | | 4 | mA |
| t _{ui} | Input pulse width | 1 | | | μs |
| 1/t _{ui} | Signaling rate | 0 | 1500 ⁽²⁾ | 1000 | kbps |
| V _{IH} | High-level input voltage (IN) (EN on all devices) | 2 | | V _{CC} | V |
| V _{IL} | Low-level input voltage (IN) (EN on all devices) | 0 | | 0.8 | |
| T _J | Junction temperature | | | 150 | °C |
| H | External magnetic field-strength immunity per IEC 61000-4-8 and IEC 61000-4-9 certification | | | 1000 | A/m |

- (1) For the 5V operation, V_{CC1} or V_{CC2} is specified from 4.5V to 5.5V.
For the 3V operation, V_{CC1} or V_{CC2} is specified from 3.15V to 3.6V.
- (2) Typical signaling rate under ideal conditions at 25°C.

**ISO7230A
ISO7231A**

SLLS906C –MAY 2008–REVISED JUNE 2011

www.ti.com

ELECTRICAL CHARACTERISTICS: V_{CC1} and V_{CC2} at 5V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|--------------------------------|-----------|---|-----------------------|-----|-----|-------|
| SUPPLY CURRENT | | | | | | | |
| I _{CC1} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₂ at 3V | | 1 | 3 | mA |
| | | 1 Mbps | | | 1 | 3 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₁ at 3V, EN ₂ at 3V | | 6.5 | 11 | mA |
| | | 1 Mbps | | | 6.5 | 11 | |
| I _{CC2} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₂ at 3V | | 15 | 22 | mA |
| | | 1 Mbps | | | 16 | 22 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₁ at 3V, EN ₂ at 3V | | 13 | 20 | mA |
| | | 1 Mbps | | | 13 | 20 | |
| ELECTRICAL CHARACTERISTICS | | | | | | | |
| I _{OFF} | Sleep mode output current | | EN at 0V, Single channel | | 0 | | μA |
| V _{OH} | High-level output voltage | | I _{OH} = −4mA, See Figure 1 | V _{CC} − 0.8 | | | V |
| | | | I _{OH} = −20μA, See Figure 1 | V _{CC} − 0.1 | | | |
| V _{OL} | Low-level output voltage | | I _{OL} = 4mA, See Figure 1 | | | 0.4 | V |
| | | | I _{OL} = 20μA, See Figure 1 | | | 0.1 | |
| V _{I(HYS)} | Input voltage hysteresis | | | | 150 | | mV |
| I _{IH} | High-level input current | | IN from 0V to V _{CC} | | | 10 | μA |
| I _{IL} | Low-level input current | | | | −10 | | |
| C _I | Input capacitance to ground | | IN at V _{CC} , V _I = 0.4 sin (4E6πt) | | 2 | | pF |
| CMTI | Common-mode transient immunity | | V _I = V _{CC} or 0V, See Figure 4 | 25 | 50 | | kV/μs |

- (1) For the 5V operation, V_{CC1} or V_{CC2} is specified from 4.5V to 5.5V.
For the 3V operation, V_{CC1} or V_{CC2} is specified from 3.15V to 3.6V.

SWITCHING CHARACTERISTICS: V_{CC1} and V_{CC2} at 5V OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|---|------------------------------|-----|-----|-----|---------|
| t_{PLH} , t_{PHL} | Propagation delay | See Figure 1 | 40 | | 95 | ns |
| PWD | Pulse-width distortion ⁽¹⁾ $ t_{PHL} - t_{PLH} $ | | | | 10 | |
| $t_{sk(o)}$ | Channel-to-channel output skew ⁽²⁾ | | | 0 | 2 | ns |
| t_r | Output signal rise time | See Figure 1 | | 2 | | ns |
| t_f | Output signal fall time | | | 2 | | |
| t_{PHZ} | Propagation delay, high-level-to-high-impedance output | See Figure 2 | | 15 | 20 | ns |
| t_{PZH} | Propagation delay, high-impedance-to-high-level output | | | 15 | 20 | |
| t_{PLZ} | Propagation delay, low-level-to-high-impedance output | | | 15 | 20 | |
| t_{PZL} | Propagation delay, high-impedance-to-low-level output | | | 15 | 20 | |
| t_{fs} | Failsafe output delay time from input power loss | See Figure 3 | | 12 | | μs |

- (1) Also referred to as pulse skew.
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

ELECTRICAL CHARACTERISTICS: V_{CC1} at 5V, V_{CC2} at 3.3V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|----------------------------|--------------------------------|-----------|---|--|-----------------------|-----------------------|-----|-------|
| SUPPLY CURRENT | | | | | | | | |
| I _{CC1} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₂ at 3V | | | 1 | 3 | mA |
| | | 1 Mbps | | | | 1 | 3 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₁ at 3V, EN ₂ at 3V | | | 6.5 | 11 | mA |
| | | 1 Mbps | | | | 6.5 | 11 | |
| I _{CC2} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₂ at 3V | | | 9 | 15 | mA |
| | | 1 Mbps | | | | 9.5 | 15 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₁ at 3V, EN ₂ at 3V | | | 8 | 12 | mA |
| | | 1 Mbps | | | | 8 | 12 | |
| ELECTRICAL CHARACTERISTICS | | | | | | | | |
| I _{OFF} | Sleep mode output current | | EN at 0 V, Single channel | | | 0 | | μA |
| V _{OH} | High-level output voltage | | I _{OH} = −4mA, See Figure 1 | | ISO7230 | V _{CC} − 0.4 | | V |
| | | | | | ISO7231 (5-V side) | V _{CC} − 0.8 | | |
| | | | I _{OH} = −20μA, See Figure 1 | | V _{CC} − 0.1 | | | |
| V _{OL} | Low-level output voltage | | I _{OL} = 4mA, See Figure 1 | | | 0.4 | | V |
| | | | I _{OL} = 20μA, See Figure 1 | | | 0.1 | | |
| V _{I(HYS)} | Input voltage hysteresis | | | | | 150 | | mV |
| I _{IH} | High-level input current | | IN from 0V to V _{CC} | | | 10 | | μA |
| I _{IL} | Low-level input current | | | | | −10 | | |
| C _I | Input capacitance to ground | | IN at V _{CC} , V _I = 0.4 sin (4E6πt) | | | 2 | | pF |
| CMTI | Common-mode transient immunity | | V _I = V _{CC} or 0 V, See Figure 4 | | | 25 | 50 | kV/μs |

- (1) For the 5-V operation, V_{CC1} or V_{CC2} is specified from 4.5V to 5.5V.
For the 3V operation, V_{CC1} or V_{CC2} is specified from 3.15 V to 3.6 V.

SWITCHING CHARACTERISTICS: V_{CC1} at 5V, V_{CC2} at 3.3V OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------------|--|----------|-----------------|-----|-----|-----|------|
| t _{PLH} , t _{PHL} | Propagation delay, low-to-high-level output | ISO723xA | See Figure 1 | 40 | 100 | 11 | ns |
| PWD | Pulse-width distortion ⁽¹⁾ t _{PHL} – t _{PLH} | | | | | | |
| t _{sk(o)} | Channel-to-channel output skew ⁽²⁾ | ISO723xA | | | 0 | 2.5 | ns |
| t _r | Output signal rise time | | See Figure 1 | | 2 | 2 | ns |
| t _f | Output signal fall time | | | | | | |
| t _{PHZ} | Propagation delay, high-level-to-high-impedance output | | See Figure 2 | | 15 | 20 | ns |
| t _{PZH} | Propagation delay, high-impedance-to-high-level output | | | | | | |
| t _{PLZ} | Propagation delay, low-level-to-high-impedance output | | | | | | |
| t _{PZL} | Propagation delay, high-impedance-to-low-level output | | | | | | |
| t _{fs} | Failsafe output delay time from input power loss | | See Figure 3 | | 18 | | μs |

- (1) Also known as pulse skew
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

**ISO7230A
ISO7231A**

SLLS906C –MAY 2008–REVISED JUNE 2011

www.ti.com

ELECTRICAL CHARACTERISTICS: V_{CC1} at 3.3V, V_{CC2} at 5V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|----------------------------|--------------------------------|-----------|---|--|--------------------|-----------------------|-----|-------|
| SUPPLY CURRENT | | | | | | | | |
| I _{CC1} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₂ at 3V | | 0.5 | | 1 | mA |
| | | 1 Mbps | | | 1 | | 2 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₁ at 3V, EN ₂ at 3V | | 4.5 | | 7 | mA |
| | | 1 Mbps | | | 4.5 | | 7 | |
| I _{CC2} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₂ at 3V | | 15 | | 22 | mA |
| | | 1 Mbps | | | 16 | | 22 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, All channels, no load, EN ₁ at 3V, EN ₂ at 3V | | 13 | | 20 | mA |
| | | 1 Mbps | | | 13 | | 20 | |
| ELECTRICAL CHARACTERISTICS | | | | | | | | |
| I _{OFF} | Sleep mode output current | | EN at 0V, Single channel | | | 0 | | μA |
| V _{OH} | High-level output voltage | | I _{OH} = −4mA, See Figure 1 | | ISO7230 | V _{CC} − 0.4 | | V |
| | | | | | ISO7231 (5-V side) | V _{CC} − 0.8 | | |
| | | | I _{OH} = −20μA, See Figure 1 | | | V _{CC} − 0.1 | | |
| V _{OL} | Low-level output voltage | | I _{OL} = 4mA, See Figure 1 | | | 0.4 | | V |
| | | | I _{OL} = 20μA, See Figure 1 | | | 0.1 | | |
| V _{I(HYS)} | Input voltage hysteresis | | | | | 150 | | mV |
| I _{IH} | High-level input current | | IN from 0V to V _{CC} | | | 10 | | μA |
| I _{IL} | Low-level input current | | | | | −10 | | |
| C _I | Input capacitance to ground | | IN at V _{CC} , V _I = 0.4 sin (4E6πt) | | | 2 | | pF |
| CMTI | Common-mode transient immunity | | V _I = V _{CC} or 0V, See Figure 4 | | | 25 | 50 | kV/μs |

- (1) For 5V operation, V_{CC1} or V_{CC2} is specified from 4.5V to 5.5V.
For 3V operation, V_{CC1} or V_{CC2} is specified from 3.15V to 3.6V.

SWITCHING CHARACTERISTICS: V_{CC1} at 3.3V and V_{CC2} at 5V OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------------|--|----------|-----------------|-----|-----|-----|------|
| t _{PLH} , t _{PHL} | Propagation delay | ISO723xA | See Figure 1 | 40 | | 100 | ns |
| PWD | Pulse-width distortion ⁽¹⁾ t _{PHL} – t _{PLH} | | | | 11 | | |
| t _{sk(o)} | Channel-to-channel output skew ⁽²⁾ | ISO723xA | | | 0 | 2.5 | ns |
| t _r | Output signal rise time | | See Figure 1 | | 2 | | ns |
| t _f | Output signal fall time | | | | 2 | | |
| t _{PHZ} | Propagation delay, high-level-to-high-impedance output | | See Figure 2 | | 15 | 20 | ns |
| t _{PZH} | Propagation delay, high-impedance-to-high-level output | | | | 15 | 20 | |
| t _{PLZ} | Propagation delay, low-level-to-high-impedance output | | | | 15 | 20 | |
| t _{PZL} | Propagation delay, high-impedance-to-low-level output | | | | 15 | 20 | |
| t _{fs} | Failsafe output delay time from input power loss | | See Figure 3 | | 12 | | μs |

- (1) Also known as pulse skew
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

ELECTRICAL CHARACTERISTICS: V_{CC1} and V_{CC2} at 3.3V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|--------------------------------|-----------|---|-----|-----------------------|-----|-------|
| SUPPLY CURRENT | | | | | | | |
| I _{CC1} | ISO7230A | Quiescent | V _I = V _{CC} or 0 V, all channels, no load, EN ₂ at 3V | | 0.5 | 1 | mA |
| | | 1 Mbps | | | 1 | 2 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, all channels, no load, EN ₁ at 3V, EN ₂ at 3V | | 4.5 | 7 | mA |
| | | 1 Mbps | | | 4.5 | 7 | |
| I _{CC2} | ISO7230A | Quiescent | V _I = V _{CC} or 0V, all channels, no load, EN ₂ at 3V | | 9 | 15 | mA |
| | | 1 Mbps | | | 9.5 | 15 | |
| | ISO7231A | Quiescent | V _I = V _{CC} or 0V, all channels, no load, EN ₁ at 3V, EN ₂ at 3V | | 8 | 12 | mA |
| | | 1 Mbps | | | 8 | 12 | |
| ELECTRICAL CHARACTERISTICS | | | | | | | |
| I _{OFF} | Sleep mode output current | | EN at 0V, single channel | | 0 | | μA |
| V _{OH} | High-level output voltage | | I _{OH} = −4mA, See Figure 1 | | V _{CC} − 0.4 | | V |
| | | | I _{OH} = −20μA, See Figure 1 | | V _{CC} − 0.1 | | |
| V _{OL} | Low-level output voltage | | I _{OL} = 4mA, See Figure 1 | | 0.4 | | V |
| | | | I _{OL} = 20μA, See Figure 1 | | 0.1 | | |
| V _{I(HYS)} | Input voltage hysteresis | | | | 150 | | mV |
| I _{IH} | High-level input current | | IN from 0V or V _{CC} | | 10 | | μA |
| I _{IL} | Low-level input current | | | | −10 | | |
| C _I | Input capacitance to ground | | IN at V _{CC} , V _I = 0.4 sin (4E6πt) | | 2 | | pF |
| CMTI | Common-mode transient immunity | | V _I = V _{CC} or 0V, See Figure 4 | | 25 | 50 | kV/μs |

- (1) For 5V operation, V_{CC1} or V_{CC2} is specified from 4.5V to 5.5V.
For 3V operation, V_{CC1} or V_{CC2} is specified from 3.15V to 3.6V.

SWITCHING CHARACTERISTICS: V_{CC1} and V_{CC2} at 3.3-V OPERATION

over recommended operating conditions (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------------|--|----------|------------------------------|-----|-----|-----|------|
| t _{PLH} , t _{PHL} | Propagation delay | ISO723xA | See Figure 1 | 45 | | 110 | ns |
| PWD | Pulse-width distortion ⁽¹⁾ t _{PHL} – t _{PLH} | | | | | 12 | |
| t _{sk(o)} | Channel-to-channel output skew ⁽²⁾ | ISO723xA | | | 0 | 3 | ns |
| t _r | Output signal rise time | | See Figure 1 | | 2 | | ns |
| t _f | Output signal fall time | | | | 2 | | |
| t _{PHZ} | Propagation delay, high-level-to-high-impedance output | | See Figure 2 | | 15 | 20 | ns |
| t _{PZH} | Propagation delay, high-impedance-to-high-level output | | | | 15 | 20 | |
| t _{PLZ} | Propagation delay, low-level-to-high-impedance output | | | | 15 | 20 | |
| t _{PZL} | Propagation delay, high-impedance-to-low-level output | | | | 15 | 20 | |
| t _{is} | Failsafe output delay time from input power loss | | See Figure 3 | | 18 | | μs |

- (1) Also referred to as pulse skew.
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

PARAMETER MEASUREMENT INFORMATION

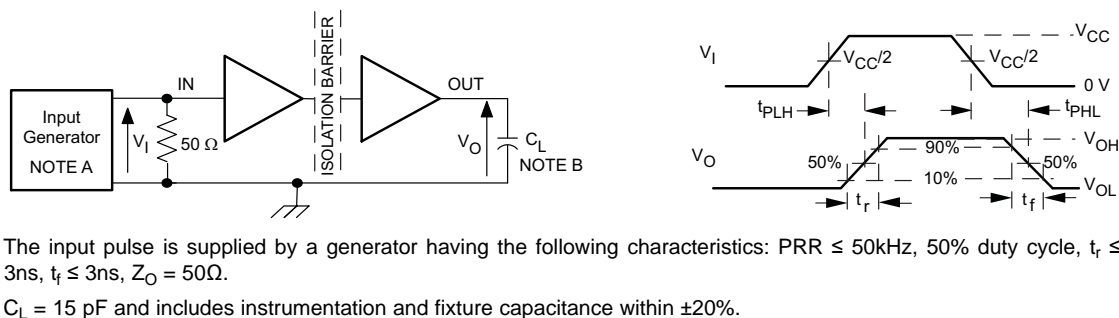


Figure 1. Switching Characteristic Test Circuit and Voltage Waveforms

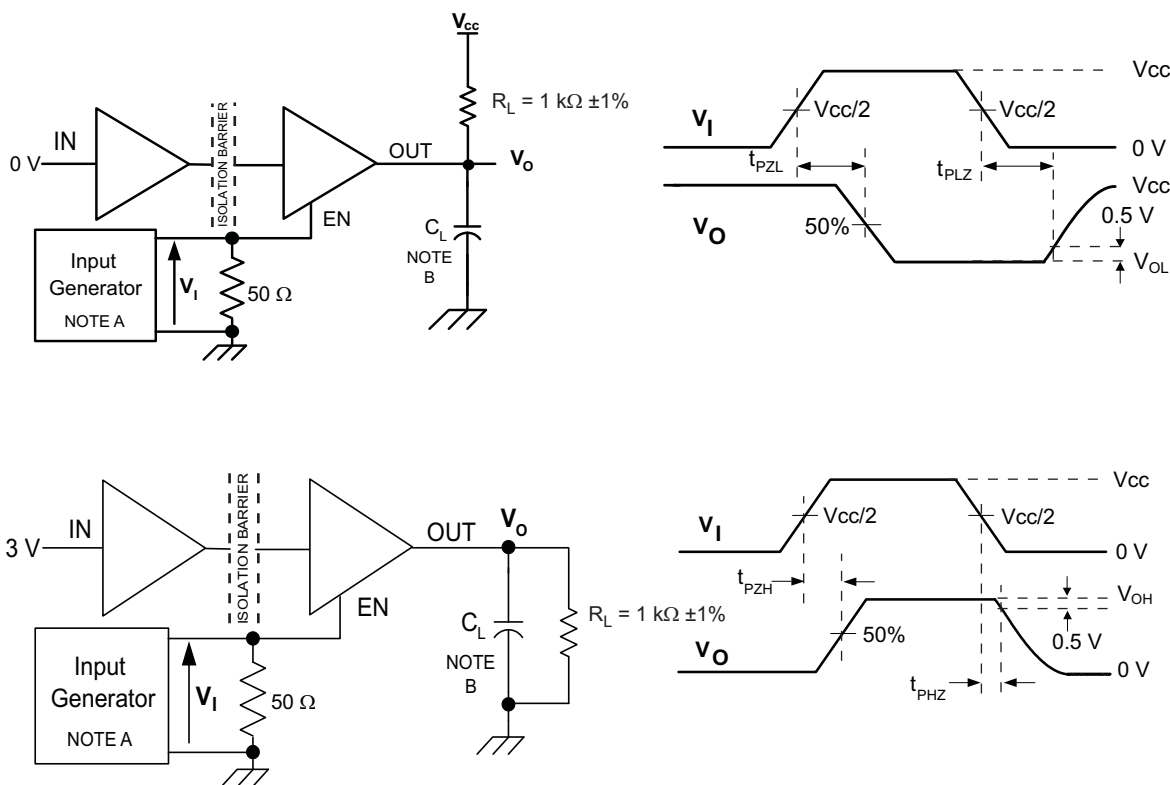
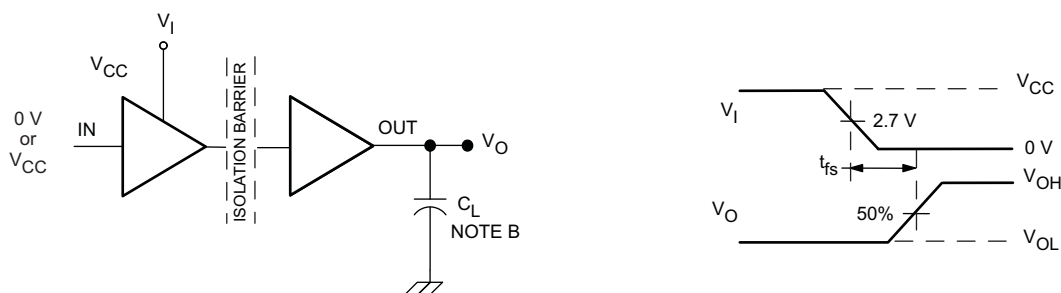


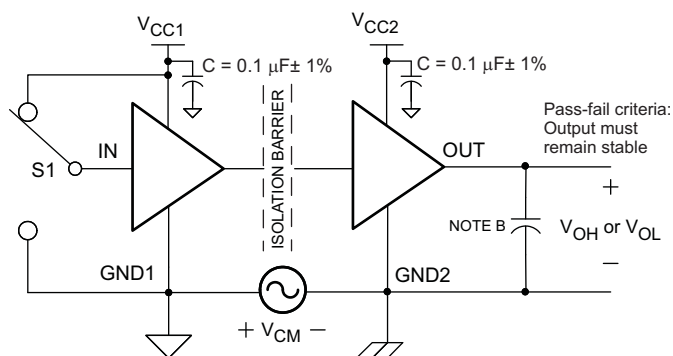
Figure 2. Enable/Disable Propagation Delay Time Test Circuit and Waveform

PARAMETER MEASUREMENT INFORMATION (continued)



- A. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 50\text{kHz}$, 50% duty cycle, $t_r \leq 3\text{ns}$, $t_f \leq 3\text{ns}$, $Z_O = 50\Omega$.
- B. $C_L = 15\text{pF}$ and includes instrumentation and fixture capacitance within $\pm 20\%$.

Figure 3. Failsafe Delay Time Test Circuit and Voltage Waveforms



- A. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 50\text{kHz}$, 50% duty cycle, $t_r \leq 3\text{ns}$, $t_f \leq 3\text{ns}$, $Z_O = 50\Omega$.
- B. $C_L = 15\text{pF}$ and includes instrumentation and fixture capacitance within $\pm 20\%$.

Figure 4. Common-Mode Transient Immunity Test Circuit and Voltage Waveform

DEVICE INFORMATION

PACKAGE CHARACTERISTICS

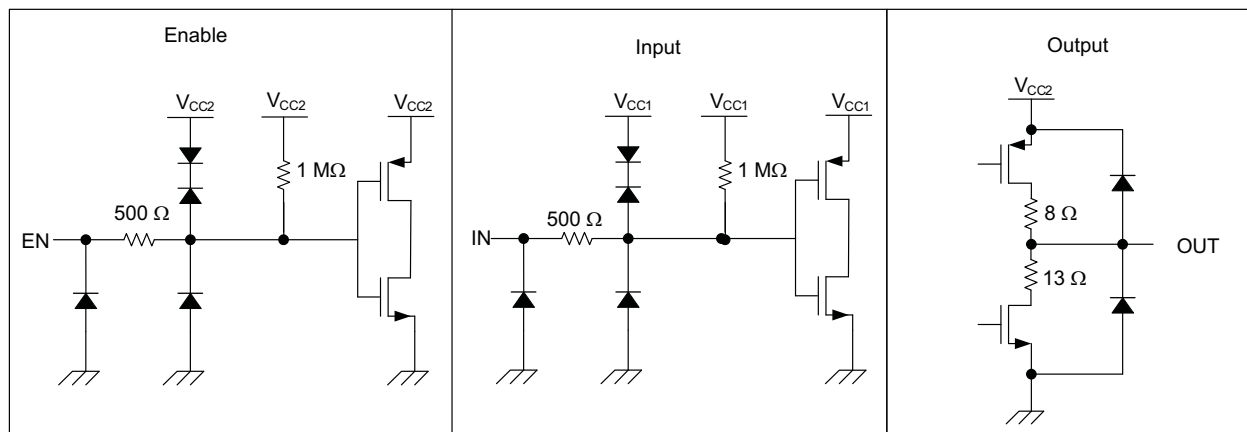
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|--|-------|-------------------|-----|------|
| L(I01) Minimum air gap (Clearance) | Shortest terminal-to-terminal distance through air | 8.34 | | | mm |
| L(I02) Minimum external tracking (Creepage) | Shortest terminal-to-terminal distance across the package surface | 8.1 | | | mm |
| Minimum Internal Gap (Internal Clearance) | Distance through the insulation | 0.008 | | | mm |
| R _{IO} Isolation resistance | Input to output, V _{IO} = 500V, all pins on each side of the barrier tied together creating a two-terminal device, T _A < 100°C | | >10 ¹² | | Ω |
| | Input to output, V _{IO} = 500V, 100°C ≤ T _A ≤ T _A max | | >10 ¹¹ | | Ω |
| C _{IO} Barrier capacitance Input to output | V _I = 0.4 sin (4E6πt) | | 2 | | pF |
| C _I Input capacitance to ground | V _I = 0.4 sin (4E6πt) | | 2 | | pF |

REGULATORY INFORMATION

| VDE | CSA | UL |
|--------------------------------------|--|--|
| Certified according to IEC 60747-5-2 | Approved under CSA Component Acceptance Notice | Recognized under 1577 Component Recognition Program ⁽¹⁾ |
| File Number: 40016131 | File Number: 220991 | File Number: E181974 |

(1) Production tested ≥ 3000 VRMS for 1 second in accordance with UL 1577.

DEVICE I/O SCHEMATICS



THERMAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|---|-----|------|-----|------|
| θ_{JA} Junction-to-air | Low-K Thermal Resistance ⁽¹⁾ | | 168 | | °C/W |
| | High-K Thermal Resistance | | 96.1 | | |
| θ_{JB} Junction-to-Board Thermal Resistance | | | 61 | | °C/W |
| θ_{JC} Junction-to-Case Thermal Resistance | | | 48 | | °C/W |
| P_D Device Power Dissipation | $V_{CC1} = V_{CC2} = 5.5\text{ V}$, $T_J = 150^\circ\text{C}$, $C_L = 15\text{ pF}$, Input a 50% duty cycle square wave | | | 220 | mW |

(1) Tested in accordance with the Low-K or High-K thermal metric definitions of EIA/JESD51-3 for leaded surface mount packages.

TYPICAL CHARACTERISTIC CURVES

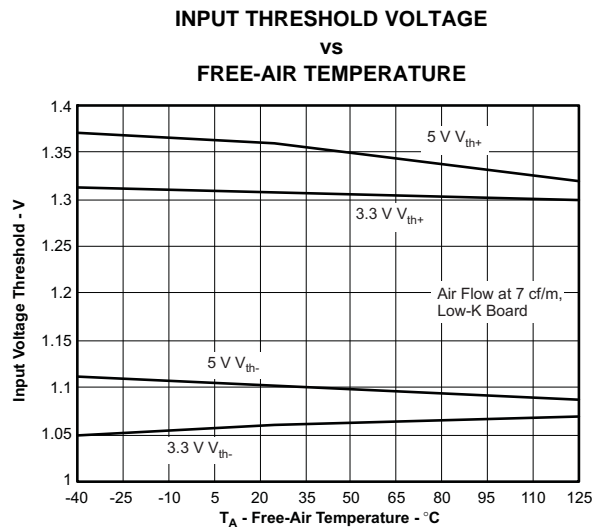


Figure 5.

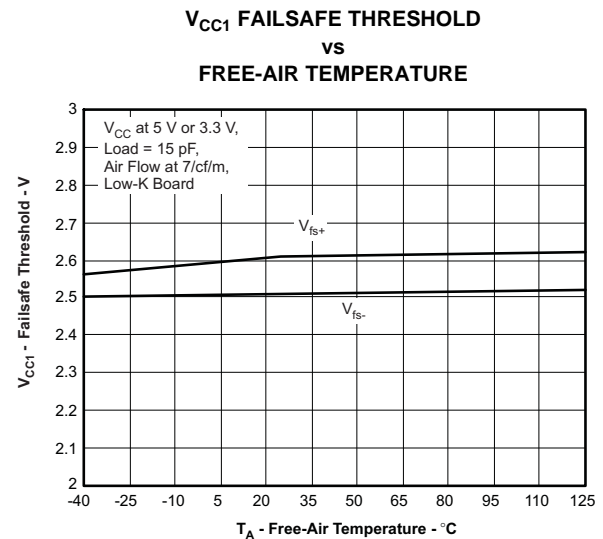


Figure 6.

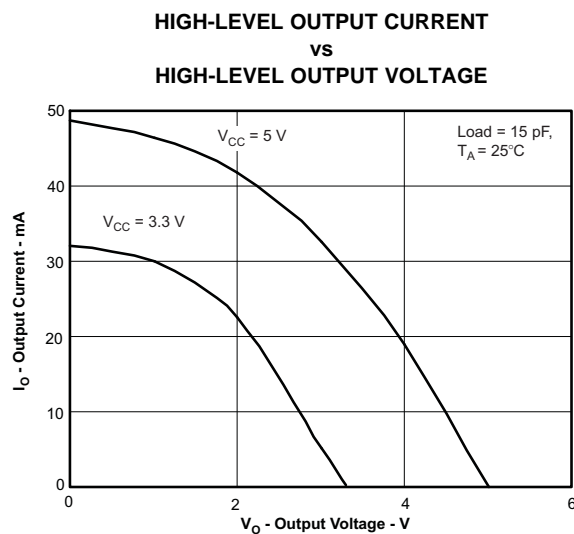


Figure 7.

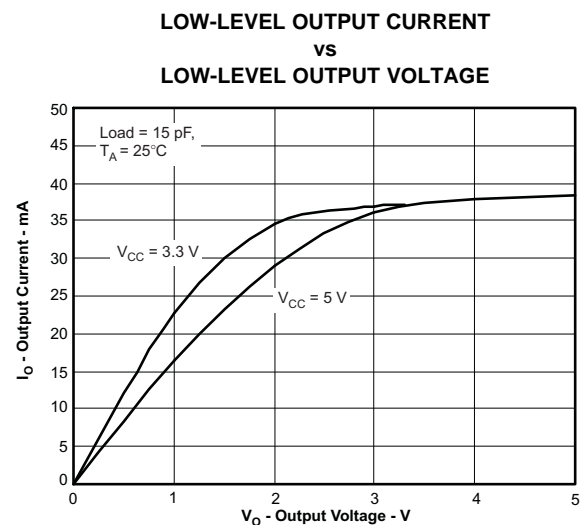


Figure 8.

APPLICATION INFORMATION

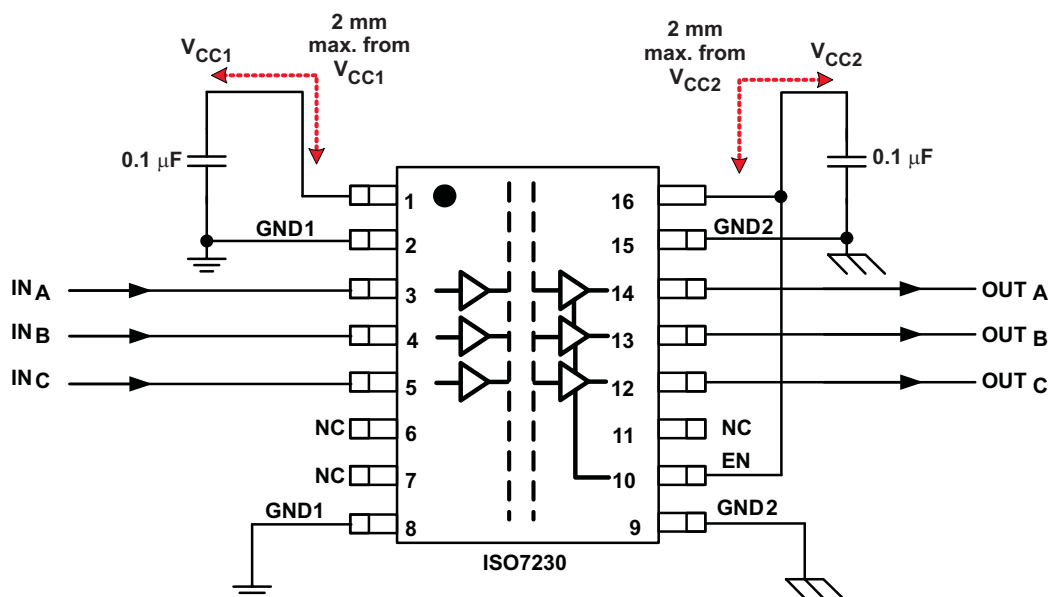


Figure 9. Typical ISO7230 Application Circuit

LIFE EXPECTANCY vs WORKING VOLTAGE

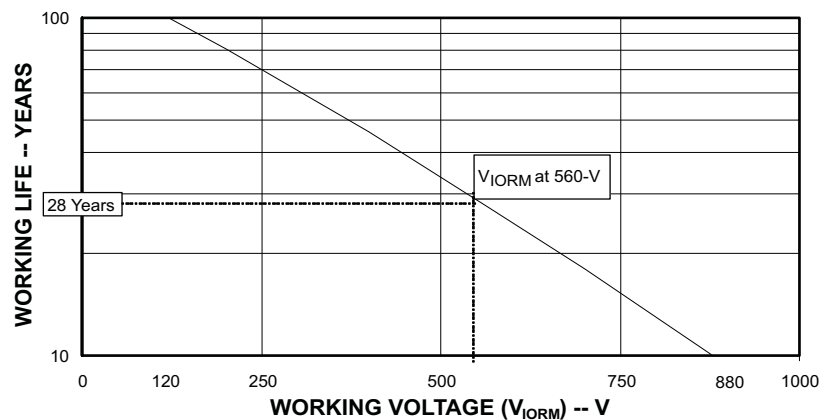


Figure 10. Time Dependant Dielectric Breakdown Testing Results

PRODUCT NOTIFICATION

An ISO723xA anomaly occurs when a negative-going pulse below the specified 1 μ s minimum bit width is input to the device. The output locks in a logic-low condition until the next rising edge occurs after a 1 μ s period.

Positive noise edges in pulses of less than the minimum specified 1 μ s have no effect on the device, and are properly filtered.

To prevent noise from interfering with ISO723xA performance, it is recommended that an appropriately sized capacitor be placed on each input of the device

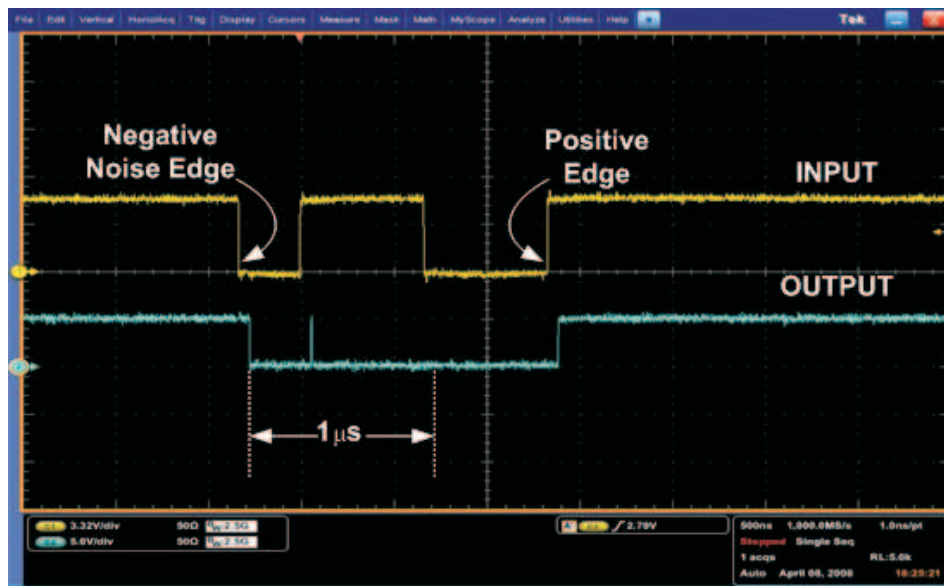


Figure 11. ISO723xA Anomaly

REVISION HISTORY

| Changes from Original (May 2008) to Revision A | Page |
|---|------|
| • Added Product Notification section link. | 1 |
| • Deleted text from paragraph 2 of the Description: "and turns off internal bias circuitry to conserve power" | 1 |
| • Deleted Product Preview note | 2 |
| • Changed From: 3 To: 3.15 | 3 |
| • Changed V_{CC} From: 3.6 To: 3.45 | 3 |
| • Changed I_{CC1} and I_{CC2} values From: TBD | 4 |
| • Changed $V_{CC} - 0.4$ To: $V_{CC} - 0.8$ | 4 |
| • Changed Typical value from 1 To: 2 | 4 |
| • Changed Propagation delay max From: 80 To: 95 | 4 |
| • Changed I_{CC1} and I_{CC2} values From: TBD | 5 |
| • Changed Typical value from 1 To: 2 | 5 |
| • Changed Propagation delay max From: 80 To: 100 | 5 |
| • Changed I_{CC1} and I_{CC2} values From: TBD | 6 |
| • Changed Typical value from 1 To: 2 | 6 |
| • Changed Propagation delay max From: 80 To: 100 | 6 |
| • Changed I_{CC1} and I_{CC2} values From: TBD | 7 |
| • Changed | 7 |
| • Changed Typical value from 1 To: 2 | 7 |
| • Changed Propagation delay max From: 85 To: 110 | 7 |
| • Changed L(101) Minimum air gap (Clearance) - minimum value from: 7.7mm to: 8.34mm | 10 |
| • Changed Typical value from 1 To: 2 | 10 |
| • Changed Typical value from 1 To: 2 | 10 |
| • Changed the REGULATORY INFORMATION Table | 10 |
| • Changed Figure 11 | 13 |

| Changes from Revision A (June 2008) to Revision B | Page |
|---|------|
| • Changed V_{CC} From: 3.45 To: 3.6 | 3 |

| Changes from Revision B (July 2008) to Revision C | Page |
|---|------|
| • Changed "1ns" to "2ns", added "(5v-Operation)" | 1 |
| • Changed "2ns" to "10ns", added "(5v-Operation)" | 1 |
| • Deleted "Low Jitter Content; 1 ns Typ at 150 Mbps" | 1 |
| • Deleted Min = 4.5 V and max = 5.5 V for Supply Voltage of the ROC Table. | 3 |
| • Changed V_{CC} From: 3.6 To: 5.5 | 3 |
| • Corrected Figure 1 | 8 |
| • Changed File number "1698195" to "220991" | 10 |
| • Corrected DEVICE I/O SCHEMATICS | 10 |
| • Corrected Figure 9 | 12 |

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|-----------------------|--------------|-----------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| ISO7230ADW | NRND | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7230ADWG4 | NRND | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7230ADWR | NRND | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7230ADWRG4 | NRND | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7231ADW | NRND | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7231ADWG4 | NRND | SOIC | DW | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7231ADWR | NRND | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |
| ISO7231ADWRG4 | NRND | SOIC | DW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ISO7230ADWR | SOIC | DW | 16 | 2000 | 330.0 | 16.4 | 10.75 | 10.7 | 2.7 | 12.0 | 16.0 | Q1 |
| ISO7231ADWR | SOIC | DW | 16 | 2000 | 330.0 | 16.4 | 10.75 | 10.7 | 2.7 | 12.0 | 16.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ISO7230ADWR | SOIC | DW | 16 | 2000 | 367.0 | 367.0 | 38.0 |
| ISO7231ADWR | SOIC | DW | 16 | 2000 | 367.0 | 367.0 | 38.0 |

DW (R-PDSO-G16)

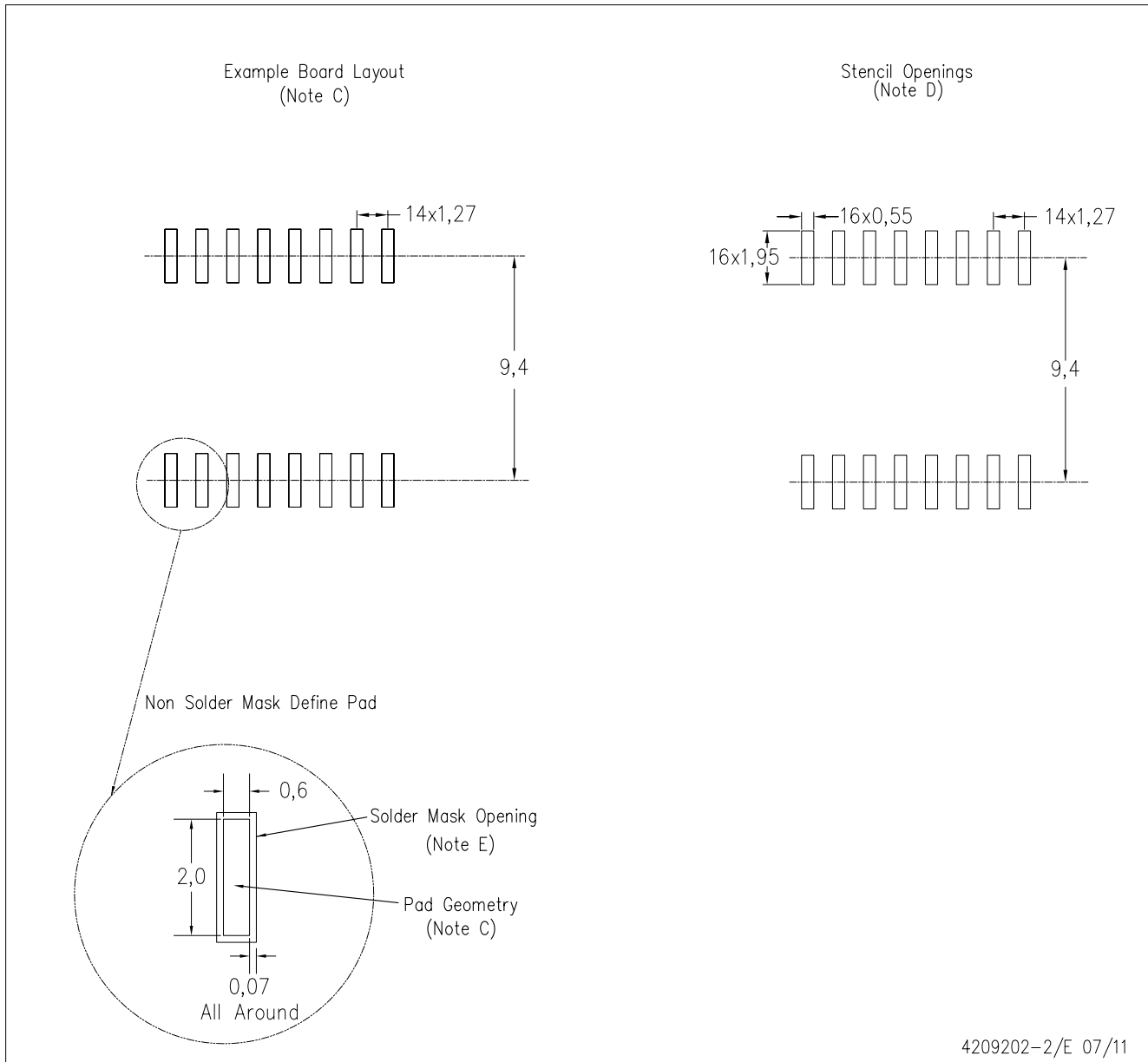
PLASTIC SMALL OUTLINE



- NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-013 variation AA.

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Refer to IPC7351 for alternate board design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46C and to discontinue any product or service per JESD48B. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

Products

| | |
|------------------------|--|
| Audio | www.ti.com/audio |
| Amplifiers | amplifier.ti.com |
| Data Converters | dataconverter.ti.com |
| DLP® Products | www.dlp.com |
| DSP | dsp.ti.com |
| Clocks and Timers | www.ti.com/clocks |
| Interface | interface.ti.com |
| Logic | logic.ti.com |
| Power Mgmt | power.ti.com |
| Microcontrollers | microcontroller.ti.com |
| RFID | www.ti-rfid.com |
| OMAP Mobile Processors | www.ti.com/omap |
| Wireless Connectivity | www.ti.com/wirelessconnectivity |

Applications

| | |
|-------------------------------|--|
| Automotive and Transportation | www.ti.com/automotive |
| Communications and Telecom | www.ti.com/communications |
| Computers and Peripherals | www.ti.com/computers |
| Consumer Electronics | www.ti.com/consumer-apps |
| Energy and Lighting | www.ti.com/energy |
| Industrial | www.ti.com/industrial |
| Medical | www.ti.com/medical |
| Security | www.ti.com/security |
| Space, Avionics and Defense | www.ti.com/space-avionics-defense |
| Video and Imaging | www.ti.com/video |

TI E2E Community e2e.ti.com

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692
Email amall@ameya360.com
QQ 800077892
Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333
Email mkt@ameya360.com